

First Named Inventor	Chun Chen
Serial No.	10/662,074
Filing Date	September 12, 2003
Group Art Unit	Unknown
Examiner Name	Unknown
Confirmation No.	9792
Attorney Docket No.	400.181US03

**GENERAL
TRANSMITTAL
FORM UNDER 37 CFR 1.8
(LARGE ENTITY)**

Title: CONTACTLESS UNIFORM-TUNNELING SEPARATE P-WELL (CUSP) NON-VOLATILE MEMORY ARRAY ARCHITECTURE, FABRICATION AND OPERATION

Commissioner for Patents
P. O. Box 1450
Alexandria, VA 22313-1450

Enclosures

The following documents are enclosed:

- ☒ Form 1449 (1 pg.);
- ☒ Supplemental Information Disclosure Statement (1 pg.);
- ☒ An itemized return-receipt postcard

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**Please charge any additional fees or credit any overpayments
to Deposit Account No. 501373.**

CUSTOMER NO. 27073

Submitted By

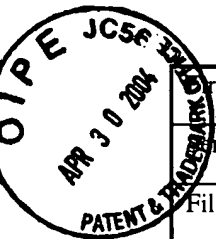
Name	Andrew C. Walseth	Reg. No.	43,234	Telephone	(612) 312-2207
Signature				Date	4/26/04

Certificate of Mailing

I certify that this correspondence and the identified documents listed on this transmittal are being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P. O. Box 1450, Alexandria, VA 22313-1450 on April 27, 2004.

Name	Susan W. Donovan	Signature	
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(LARGE entity transmittal under 37 CFR § 1.8)



First Named Inventor	Chun Chen	SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT
Serial No.	10/662,074	
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In compliance with 37 C.F.R. §§ 1.56 and 1.97, *et seq.*, the enclosed materials are brought to the attention of the Examiner for consideration in connection with the above-identified Application. Applicant respectfully requests that this Supplemental Information Disclosure Statement be entered and the references listed on the attached Form 1449 be considered by the Examiner and made of record. Pursuant to MPEP §609, Applicant further requests that the Examiner initial next to each reference on the Form 1449 to indicate that the listed references have been considered, and that a copy of the initialed Form 1449 be returned with the next official communication.

The enclosed references were recently cited in a communication in a counterpart foreign application. A copy of the International Search Report is enclosed herewith. As a substantive Office Action has not yet issued in this application, Applicant believes that no fees are due. However, the Commissioner for Patents is hereby authorized to charge any additional fees to Deposit Account No. 501373.

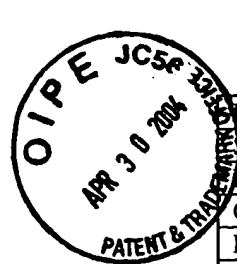
If the Examiner has any questions or concerns regarding this application, please contact the undersigned at (612) 312-2207.

Respectfully submitted,

Date: 4/26/04

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First Named Inventor	Chun Chen	INFORMATION DISCLOSURE STATEMENT FORM PTO-1449
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U.S. Patent References				
Examiner Initials	Document No.	Issue/Published Date	Name	Filing Date
	5,343,423	08/30/94	Shimoji	12/23/91
	5,691,938	11/25/97	Yiu et al.	05/03/94
	6,137,723	10/24/00	Bergemont et al.	04/28/99
	6,181,601 B1	01/30/01	Chi	12/02/99

Foreign Patent References					
Examiner Initials	Foreign Patent		Name	Publication Date	T?
	Country	No.			

Other References	
Examiner Initials	Author, Title, Date, Pages, etc.
	S. Aritome, et al. "A reliable bi-polarity write/erase technology in flash EEPROMS", Int'l. Electron Devices Meeting, 1990, <u>Technical Digest</u> , 9-12 Dec. 1990; pp. 111-114.

Examiner Signature		Date Considered	
*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.			